

## **Customer Technical Update With LAYTEC**



## Friday 13<sup>th</sup> December 2024 commencing 09:30

TIME	ТОРІС	PRESENTER
10 min	<ul> <li>Welcome, Introduction Company Overview</li> <li>Corporate Organization and Oxford Instruments Plasma Technology.</li> <li>Workshop objective.</li> </ul>	Gohda-san - Oxford Instruments
30 min	<ul> <li>InP and GaAs lasers – III-V Material         Processing         <ul> <li>Production solution for etching of InP transceivers and GaAs VCSEL.</li> <li>Etch III-V etching process overview for R&amp;D.</li> </ul> </li> </ul>	Dr Ligang Deng - Oxford Instruments
30 min	<ul> <li>SiC PE - Material Processing</li> <li>Plasma etch and deposition solutions for current and next generation SiC power devices.</li> <li>SiC substrate Epi ready cost reduction for 150mm and 200mm wafers with plasma polishing.</li> </ul>	Ian Wright - Oxford Instruments
15 min	Coffee Break sponsored by Hakuto	
30 min	<ul> <li>GaN PE/RF - Atomic Scale Processing</li> <li>Production-qualified Plasma Atomic Layer Deposition for GaN HEMT passivation.</li> <li>Low damage, reliable etch processes for p-GaN HEMT and recessed MISHEMT manufacturing.</li> </ul>	Dr Aileen O'Mahony - Oxford Instruments
20 min	<ul><li>Endpoint solutions</li><li>Leading endpoint accuracy.</li><li>End pointing materials.</li></ul>	Dr Yuto Tomita - Laytec
10 min	Wrap up and next steps  • Q&A  • Further engagement.	Robert Gunn - Oxford Instruments
60 min	Coffee light - refreshments	